

# **S2A/A - S2M/A**

# 1.5A SURFACE MOUNT GLASS PASSIVATED RECTIFIER

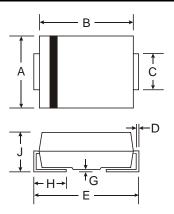
## **Features**

- Glass Passivated Die Construction
- Low Forward Voltage Drop and High Current Capability
- Surge Overload Rating to 50A Peak
- Ideally Suited for Automated Assembly
- Lead Free Finish/RoHS Compliant (Note 3)

## **Mechanical Data**

- Case: SMA/SMB
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Lead Free Plating (Matte Tin Finish).
  Solderable per MIL-STD-202, Method 208 (3)
- Polarity: Cathode Band or Cathode Notch
- Marking Information: See Page 2
- Ordering Information: See Page 2
- Approximate Weight: SMA 0.064 grams

SMB 0.093 grams



DIM	SN	/IΑ	SMB				
	Min	Max	Min	Max			
Α	2.29	2.92	3.30	3.94			
В	4.00	4.60	4.06	4.57			
С	1.27	1.63	1.96	2.21			
D	0.15	0.31	0.15	0.31			
Е	4.80	5.59	5.00	5.59			
G	0.05	0.20	0.05	0.20			
Н	0.76	1.52	0.76	1.52			
J	2.01	2.30	2.00	2.62			
All Dimensions in mm							

# Maximum Ratings and Electrical Characteristics @TA = 25°C unless otherwise specified

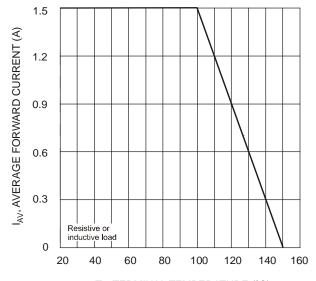
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

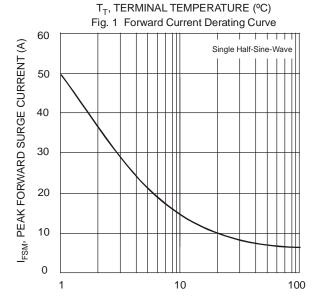
Characteristic		Symbol	S2 A/AA	S2 B/BA	S2 D/DA	S2 G/GA	S2 J/JA	S2 K/KA	S2 M/MA	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	200	400	600	800	1000	V
RMS Reverse Voltage		V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	٧
Average Rectified Output Current @ T <sub>T</sub> = 100°C		I <sub>(AV)</sub>	1.5							Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load			50							Α
Forward Voltage @ I <sub>F</sub> = 1.5A		$V_{FM}$	1.15						V	
Peak Reverse Current at Rated DC Blocking Voltage	@T <sub>A</sub> = 25°C @T <sub>A</sub> = 125°C	I <sub>RM</sub>				5.0 125				μΑ
Typical Total Capacitance (Note 1)		Ст	20							pF
Typical Thermal Resistance, Junction to Terminal (Note 2)		$R_{ heta JT}$	20							°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-65 to +150							°C

Notes:

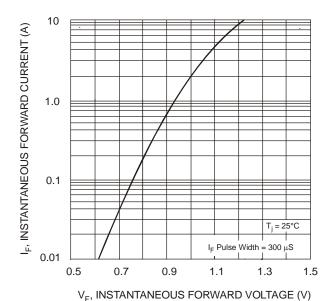
- 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.
- 2. Thermal Resistance Junction to Terminal, unit mounted on PC board with 5.0 mm² (0.013 mm thick) copper pads as heat sink.
- 3. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied, see *EU Directive 2002/95/EC Annex Notes*.

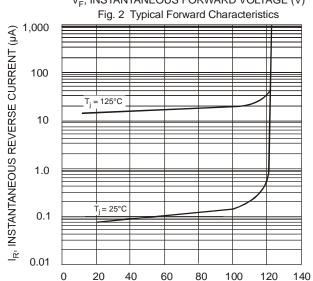






NUMBER OF CYCLES AT 60 Hz Fig. 3 Forward Surge Current Derating Curve





PERCENT OF RATED PEAK REVERSE VOLTAGE (%) Fig. 4 Typical Reverse Characteristics

#### **Ordering Information** (Note 4)

Device*	Packaging	Shipping
S2xA-13-F	SMA	5000/Tape & Reel
S2x-13-F	SMB	3000/Tape & Reel

<sup>\*</sup>x = Device type, e.g. S2AA-13-F (SMA package); S2A-13-F (SMB package).

4. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

# **Marking Information**



XXX = Product type marking code, ex: S2A (SMB package) XXXX = Product type marking code, ex: S2AA (SMA package)

⊇!! = Manufacturers' code marking

YWW = Date code marking Y = Last digit of year ex: 2 for 2002

WW = Week code 01 to 52



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